

SANYO Semiconductors DATA SHEET

P-Channel Silicon MOSFET

SFT1327 — General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- · 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-80	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	ID		-5.5	А
Drain Current (PW≤10μs)	IDP	PW≤10μs, duty cycle≤1%	-18	А
Allowable Power Dissipation	D-		1.0	W
	PD	Tc=25°C	15	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Uill
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-80			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-80V, V _{GS} =0V			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μА
Cutoff Voltage	V _{GS} (off)	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-2.3A	3.4	5.7		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =-2.3A, V _G S=-10V		137	178	mΩ
	R _{DS} (on)2	I _D =-2.3A, V _G S=-4.5V		162	227	mΩ
	R _{DS} (on)3	I _D =-2.3A, V _G S=-4V		171	239	mΩ

Marking: T1327 Continued on next page.

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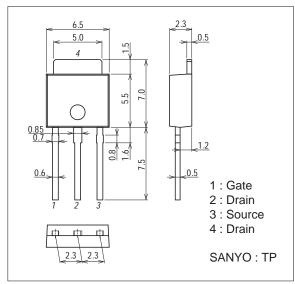
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Parameter	Cymphol	Conditions	Ratings			Linit
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss	V _{DS} =-20V, f=1MHz		1110		pF
Output Capacitance	Coss	V _{DS} =-20V, f=1MHz		75		pF
Reverse Transfer Capacitance	Crss	V _{DS} =-20V, f=1MHz		55		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		12		ns
Rise Time	t _r	See specified Test Circuit.		89		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		112		ns
Fall Time	tf	See specified Test Circuit.		45		ns
Total Gate Charge	Qg	V _{DS} =-40V, V _{GS} =-10V, I _D =-4.5A		19.7		nC
Gate-to-Source Charge	Qgs	V _{DS} =-40V, V _{GS} =-10V, I _D =-4.5A		2.9		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =-40V, V _{GS} =-10V, I _D =-4.5A		2.9		nC
Diode Forward Voltage	VSD	IS=-5.5A, VGS=0V		-0.88	-1.2	V

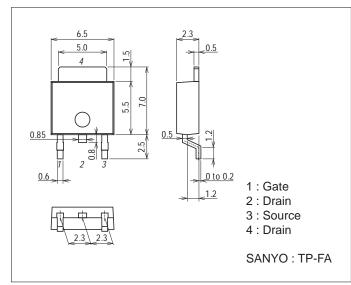
Package Dimensions

unit : mm (typ) 7518-004

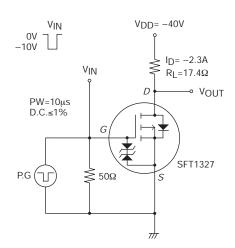


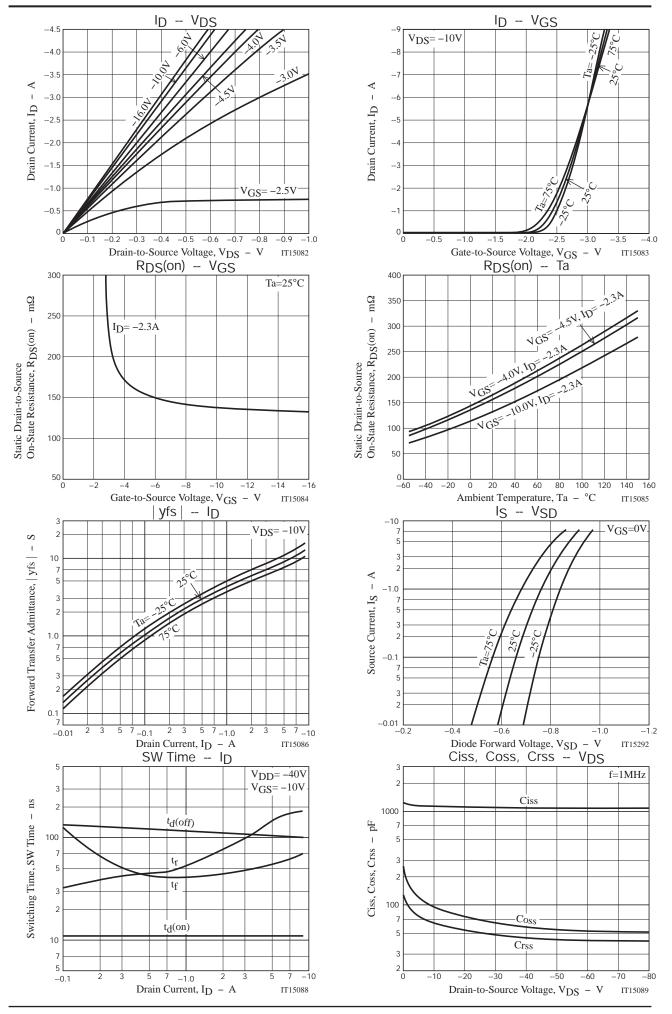
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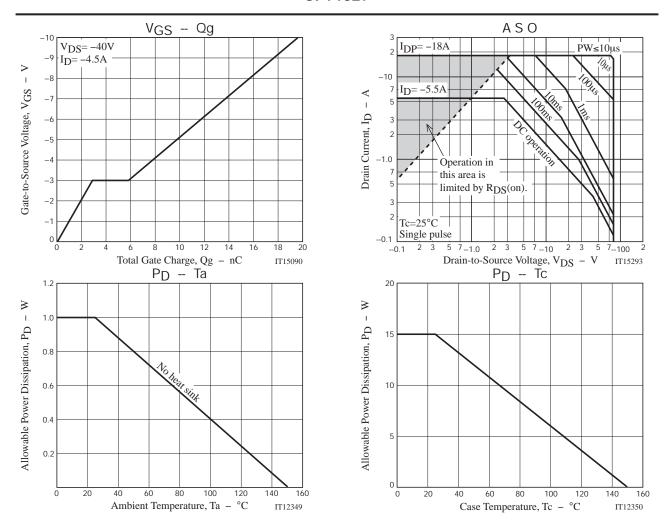
unit : mm (typ) 7003-004



Switching Time Test Circuit







Note on usage: Since the SFT1327 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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